NSN 5961-01-289-4239

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-289-4239 **Inclosure Material:** Glass **Overall Length:** Between 0.350 inches and 0.375 inches **Terminal Length:** 1.100 inches **Overall Diameter:** Between 0.190 inches and 0.205 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 68.0 breakdown voltage, dc **Current Rating Per Characteristic:** 1.00 milliamperes collector current, dc peak **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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